

60 V, 3 A PNP low VCEsat transistor

24 May 2022

1. General description

PNP low V_{CEsat} transistor in a medium power SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4360Z

2. Features and benefits

- Low collector-emitter saturation voltage V_{CEsat}
- + High collector current capability ${\rm I}_{\rm C}$ and ${\rm I}_{\rm CM}$
- High energy efficiency due to less heat generation
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- DC-to-DC conversion
- Supply line switching
- Battery charger
- LCD backlighting
- Driver in low supply voltage applications (e.g. lamps and LEDs)
- Inductive load driver (e.g. relays, buzzers and motors)

4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-60	V
I _C	collector current			-	-	-3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-6	А
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C		-	-	225	mΩ

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	2, 4
2	С	collector		
3	E	emitter		
4	С	collector		3
			SC-73 (SOT223)	sym028

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6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PBSS5360Z-Q		plastic, surface-mounted package with increased heatsink; 4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body	<u>SOT223</u>			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PBSS5360Z-Q	P5360Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

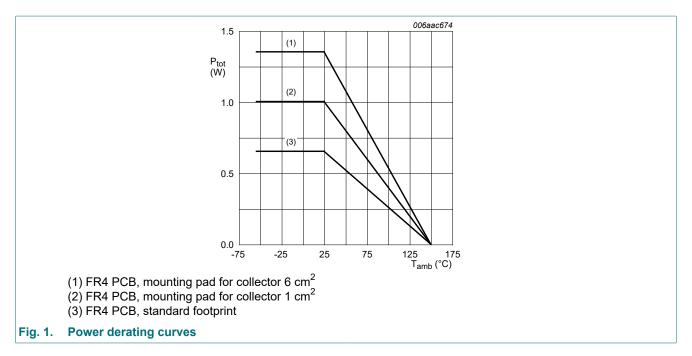
Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	-80	V
V _{CEO}	collector-emitter voltage	open base		-	-60	V
V _{EBO}	emitter-base voltage	open collector		-	-7	V
I _C	collector current			-	-3	А
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-6	А
I _B	base current			-	-500	mA
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms		-	-1	А
P _{tot}	total power dissipation		[1]	-	0.65	W
			[2]	-	1	W
			[3]	-	1.35	W
			[4]	-	2	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint. [1]

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm². Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm². [2] [3]

Device mounted on an FR4 PCB, 70 µm single-sided copper, tin-plated, mounting pad for collector 6 cm². [4]

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9. Thermal characteristics

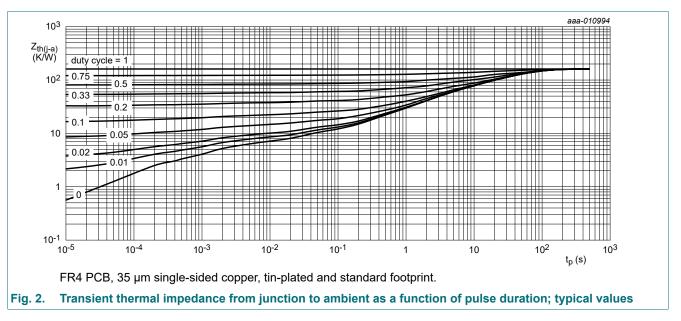
Table 6. Thermal characteristics

	ai characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	-	16	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint. [1]

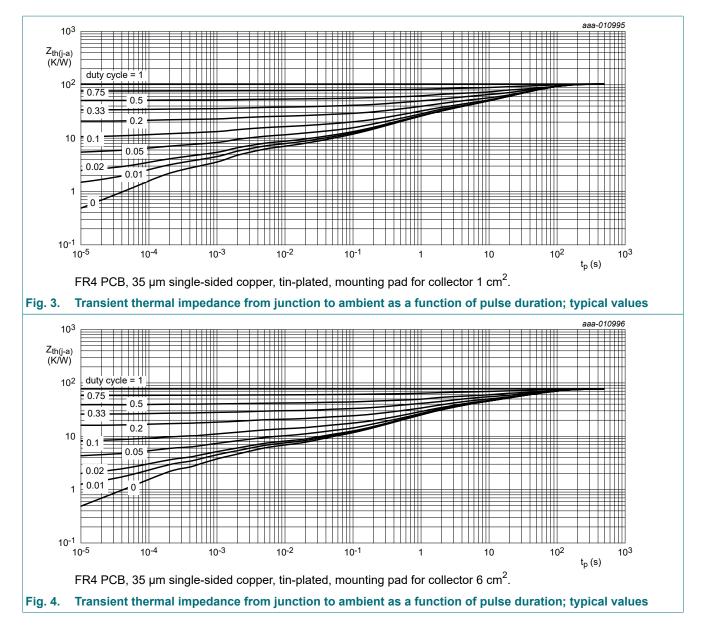
[2]

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm². Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm². [3]





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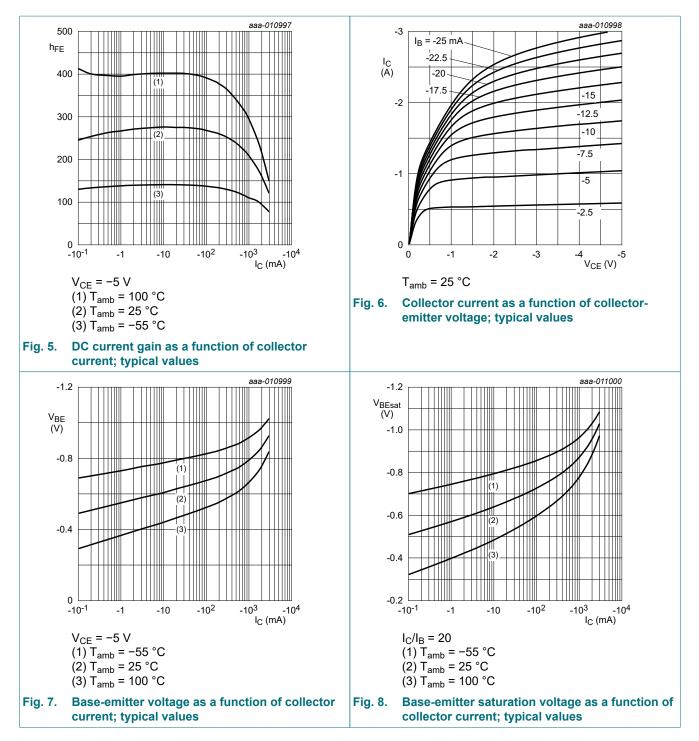


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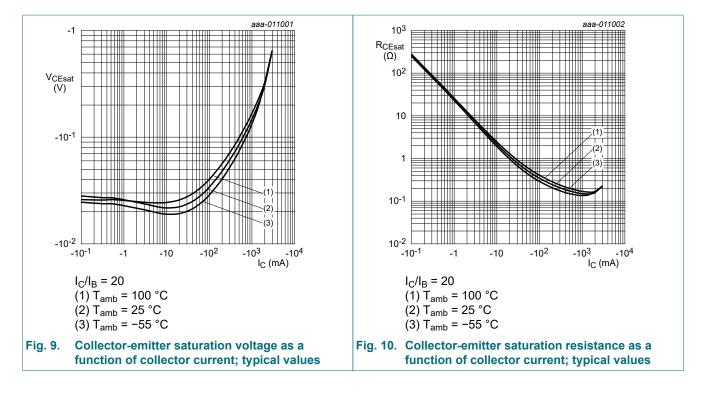
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -48 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -48 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μA
I _{CES}	collector-emitter cut-off current	V_{CE} = -48 V; V_{BE} = 0 V; T_{amb} = 25 °C	-	-	-100	nA
I _{EBO}	emitter-base cut-off current	V_{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -50 mA; T _{amb} = 25 °C	150	-	-	
		V _{CE} = -5 V; I _C = -500 mA; T _{amb} = 25 °C	130	-	-	
		V _{CE} = -5 V; I _C = -1 A; T _{amb} = 25 °C	120	-	-	
		$ \begin{array}{l} V_{CE} \texttt{=} \texttt{-5 V}; \ I_{C} \texttt{=} \texttt{-2 A}; \ t_{p} \texttt{\leq} \ \texttt{300 } \mu \texttt{s}; \ \texttt{\delta} \texttt{\leq} \\ 0.02; \ T_{amb} \texttt{=} \texttt{25 °C}; \ pulsed \end{array} $	100	-	-	
		V_{CE} = -5 V; I _C = -3 A; t _p ≤ 300 µs; δ ≤ 0.02; T _{amb} = 25 °C; pulsed	80	-	-	
V _{CEsat}	collector-emitter saturation voltage	I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	-	-	-150	mV
		$\label{eq:lc} \begin{array}{l} I_{C} = \text{-1 A; } I_{B} = \text{-100 mA; } t_{p} \leq \ 300 \ \mu\text{s; } \delta \leq \\ 0.02; \ T_{amb} = 25 \ ^\circ\text{C; pulsed} \end{array}$	-	-	-200	mV
		I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \le 300 \text{ µs}$; δ ≤ 0.02; T_{amb} = 25 °C	-	-	-450	mV
		I_{C} = -3 A; I_{B} = -300 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	-	-	-550	mV
R _{CEsat}	collector-emitter saturation resistance	I_{C} = -2 A; I_{B} = -200 mA; pulsed; $t_{p} \le 300 \ \mu s$; δ ≤ 0.02; T_{amb} = 25 °C	-	-	225	mΩ
V _{BEsat}	base-emitter saturation voltage	I _C = -1 A; I _B = -100 mA; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	-1.2	V
V _{BEon}	base-emitter turn-on voltage	V_{CE} = -5 V; I _C = -1 A; pulsed; t _p ≤ 300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	-	-1.1	V
f _T	transition frequency	V _{CE} = -10 V; I _C = -50 mA; f = 100 MHz; T _{amb} = 25 °C	65	130	-	MHz
C _c	collector capacitance	V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C	-	28	32	pF

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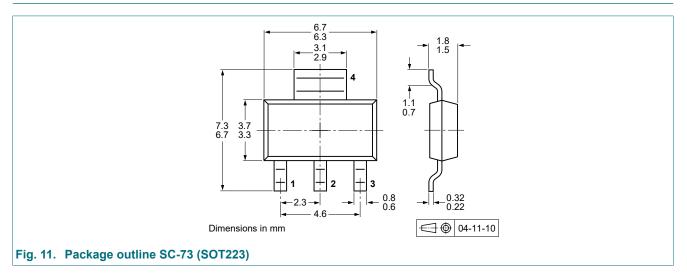


11. Test information

Quality information

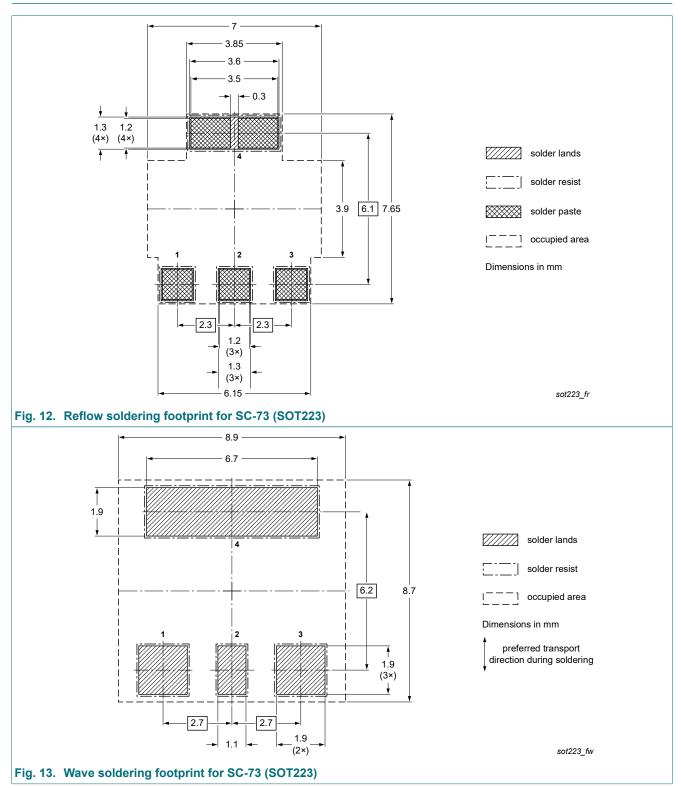
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PBSS5360Z-Q v.1	20220524	Product data sheet	-	PBSS5360Z v.1		

PBSS5360Z-Q

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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